SI7972DP-T1-GE3-VB Datasheet

Dual N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	60
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.032
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.038
Q_g typ. (nC)	7.1
I_D (A)	17
Configuration	Dual

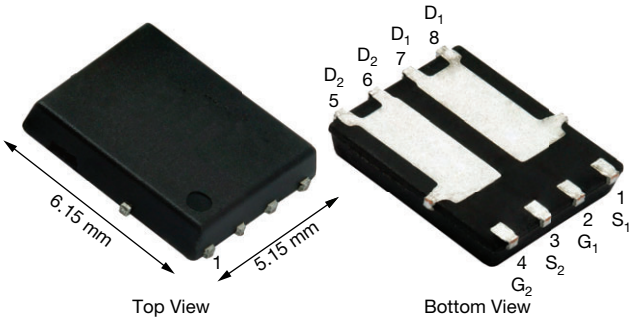
FEATURES

- TrenchFET® power MOSFET
- PWM optimized
- 100 % R_g and UIS tested

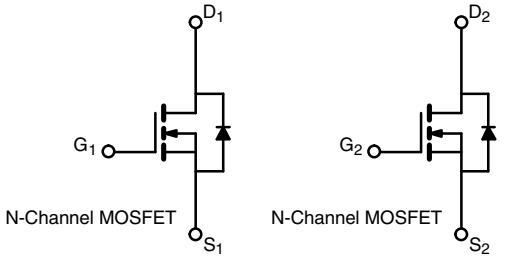
Pb-free
RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- System power DC/DC



Top View Bottom View



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	60	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	17	A
	T_C = 70 °C		8 [a]	
	T_A = 25 °C		8 [a]	
	T_A = 70 °C		8 [a]	
Pulsed drain current		I_{DM}	40	
Source-drain current diode current	T_C = 25 °C	I_S	19	
	T_A = 25 °C		3 [b, c]	
Maximum power dissipation	T_C = 25 °C	P_D	22	W
	T_C = 70 °C		14	
	T_A = 25 °C		3.6 [b, c]	
	T_A = 70 °C		2.3 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [d, e]			260	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYP.	MAX.	UNIT
Maximum junction-to-ambient [b, f]	t ≤ 10 s	R_{thJA}	26	35	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	4	5.5	

Notes

a. Package limited
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. The DFN 5x6 package is a leadless package. The end of the lead terminal is exposed copper(not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 80 °C/W

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	60	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA	-	38	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$	I_D = 250 µA	-	-4.9	-	
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1.2	-	2.7	V
Gate-body leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 60 V, V_{GS} = 0 V, T_J = 85 °C	-	-	10	
On-state drain current [b]	$I_{D(on)}$	$V_{DS} \geq$ 5 V, V_{GS} = 10 V	60	-	-	A
Drain-source on-state resistance [b]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 11 A	-	0.032	-	Ω
		V_{GS} = 4.5 V, I_D = 10 A	-	0.038	-	
Forward transconductance [b]	g_{fs}	V_{DS} = 30 V, I_D = 11 A	-	38	-	S
Dynamic [a]						
Input capacitance	C_{iss}	V_{DS} = 30 V, V_{GS} = 0 V, f = 1 MHz	-	1050	-	pF
Output capacitance	C_{oss}		-	435	-	
Reverse transfer capacitance	C_{rss}		-	20	-	
Total gate charge	Q_g	V_{DS} = 30 V, V_{GS} = 10 V, I_D = 11 A	-	15.2	23	nC
		V_{DS} = 30 V, V_{GS} = 4.5 V, I_D = 11 A	-	7.1	11	
Gate-source charge	Q_{gs}		-	4.4	-	
Gate-drain charge	Q_{gd}		-	1.3	-	
Gate resistance	R_g	f = 1 MHz	0.12	0.6	1.2	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 30 V, R_L = 3.45 Ω $I_D \cong$ 8.7 A, V_{GEN} = 4.5 V, R_g = 1 Ω	-	15	120	ns
Rise time	t_r		-	80	30	
Turn-off delay time	$t_{d(off)}$		-	15	30	
Fall time	t_f		-	15	30	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 30 V, R_L = 3.45 Ω $I_D \cong$ 8.7 A, V_{GEN} = 10 V, R_g = 1 Ω	-	10	15	
Rise time	t_r		-	25	40	
Turn-off delay time	$t_{d(off)}$		-	20	30	
Fall time	t_f		-	10	15	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode Current	I_S	T_C = 25 °C	-	-	8	A
Pulse diode forward current [a]	I_{SM}		-	-	40	
Body diode voltage	V_{SD}	I_S = 8.7 A	-	0.8	1.2	V
Body diode reverse recovery time	t_{rr}	I_F = 8.7 A, di/dt = 100 A/µs, T_J = 25 °C	-	34	51	ns
Body diode reverse recovery charge	Q_{rr}		-	30	45	nC
Reverse recovery fall time	t_a		-	16	-	ns
Reverse recovery rise time	t_b		-	18	-	

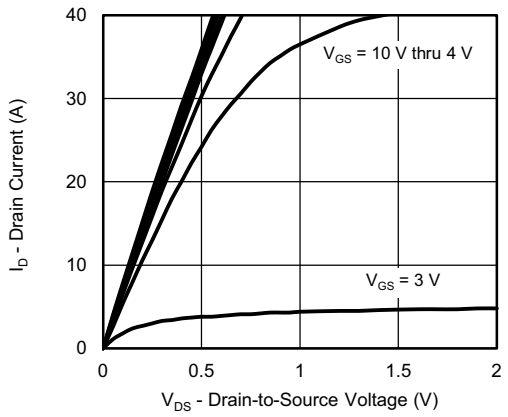
Notes

a. Guaranteed by design, not subject to production testing

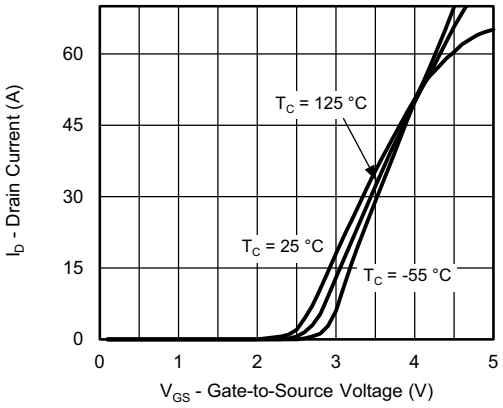
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

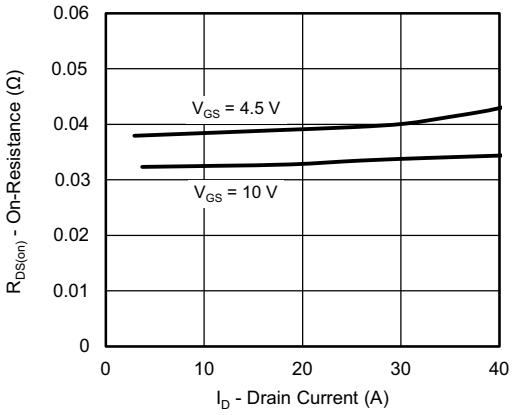
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



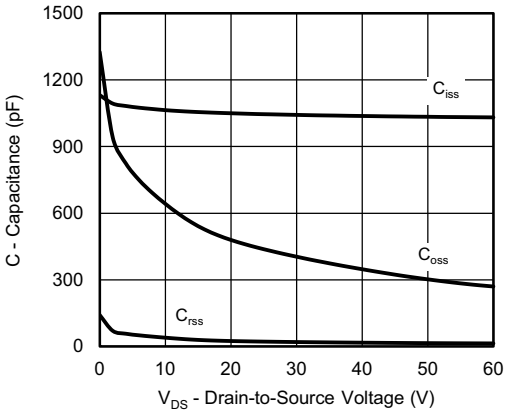
Output Characteristics



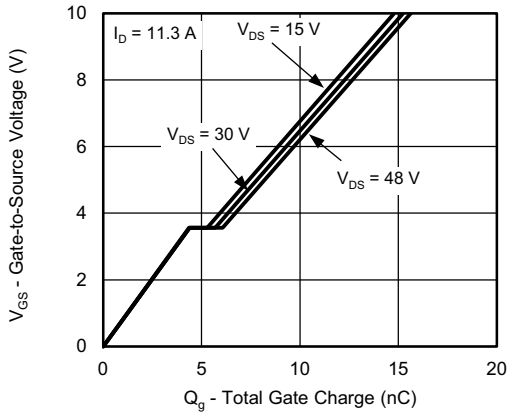
Transfer Characteristics



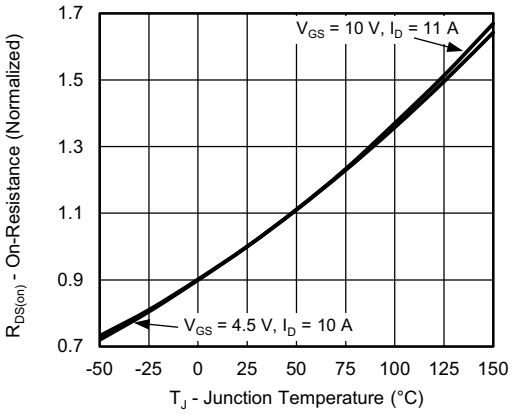
On-Resistance vs. Drain Current



Capacitance

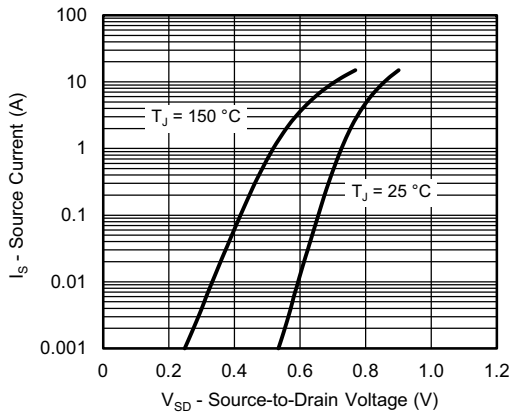


Gate Charge

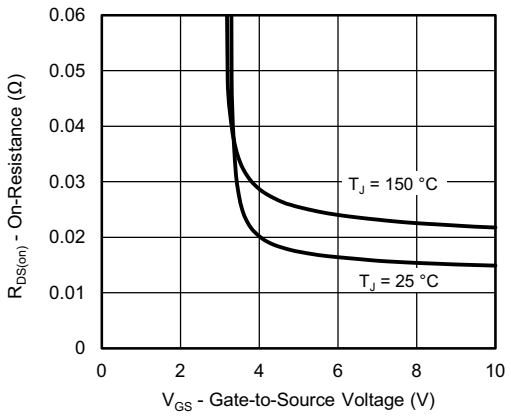


On-Resistance vs. Junction Temperature

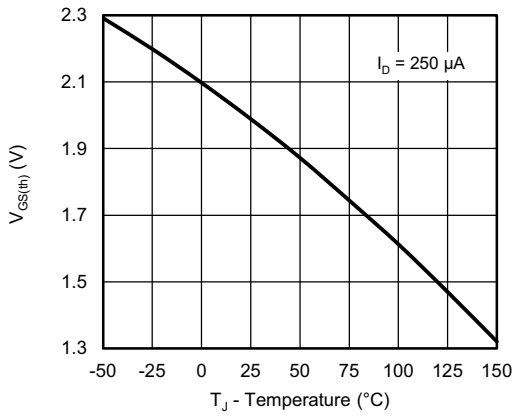
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



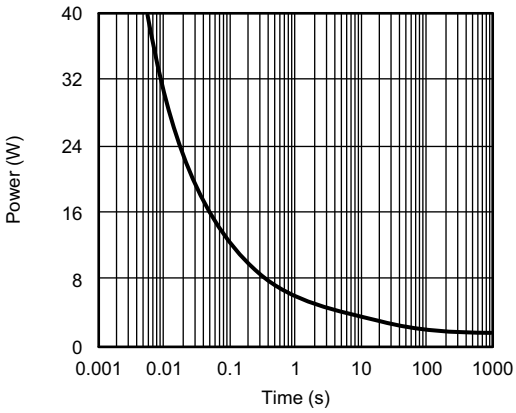
Source-Drain Diode Forward Voltage



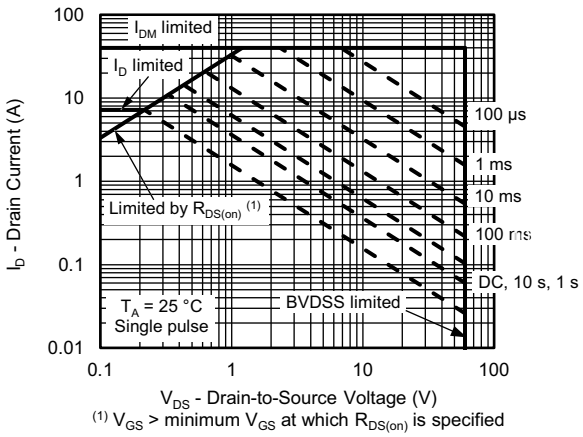
On-Resi.0stance vs. Gate-to-Source Voltage



Threshold Voltage

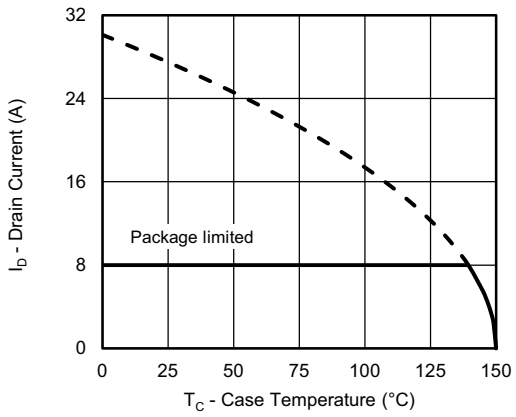


Single Pulse Power

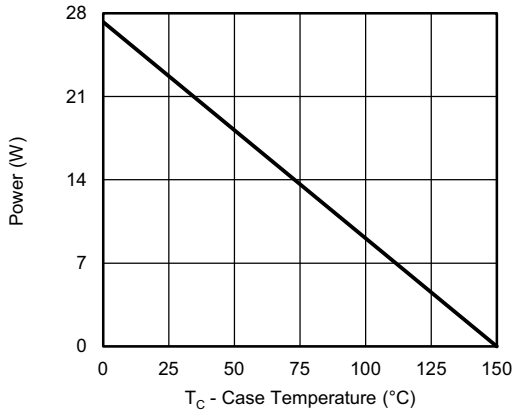


Safe Operating Area, Junction-to-Ambient

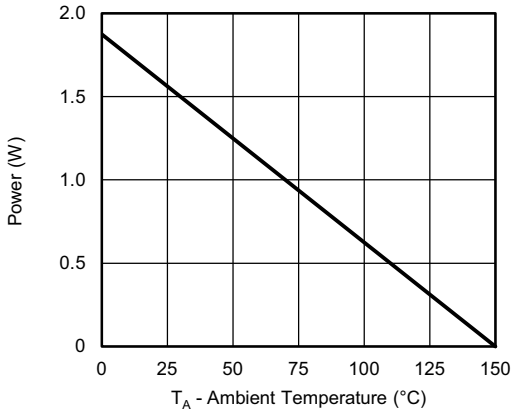
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



Power, Junction-to-Case

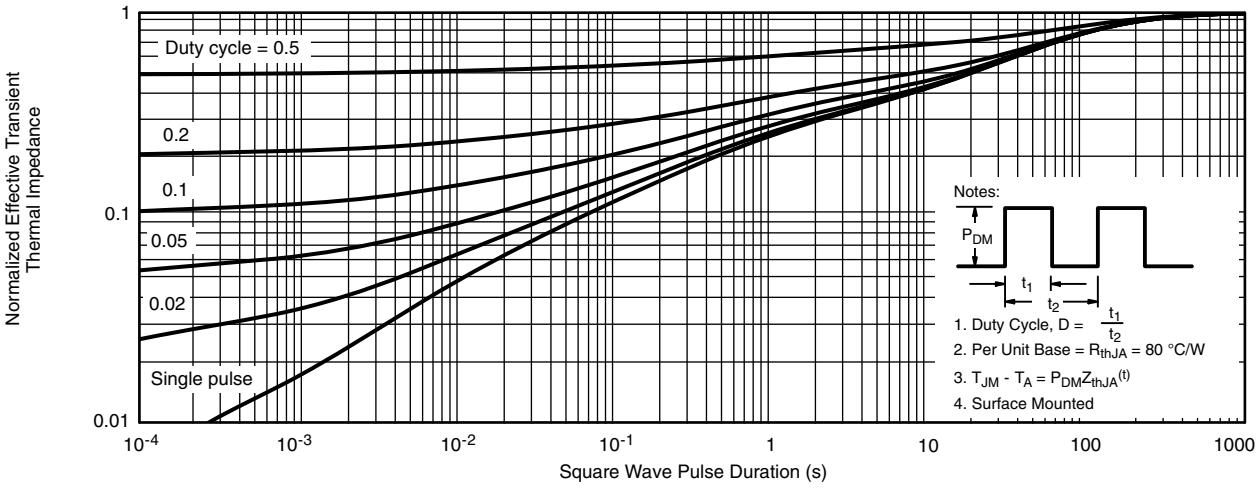


Power, Junction-to-Ambient

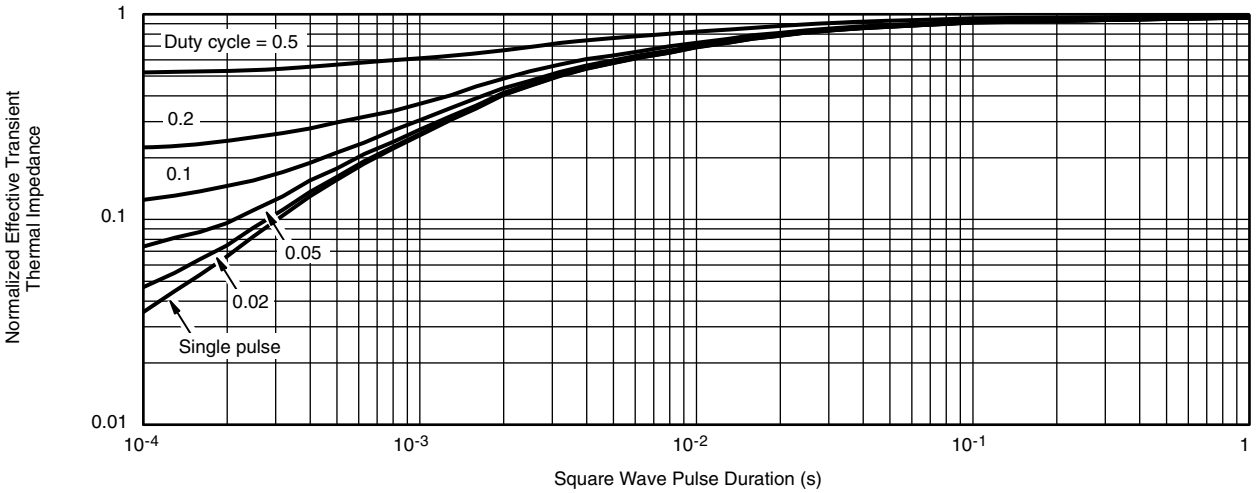
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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